NSN 5961-01-418-5362

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-418-5362

Inclosure Material:

Metal

Overall Length:

1.020 inches

Overall Height:

Between 0.147 inches and 0.167 inches

Overall Width:

Between 0.815 inches and 0.825 inches

End Application:

An/upm-155

Mounting Facility Quantity:

2

Electrode Internally-electrically Connected To Case:

Source

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 drain to gate voltage and 60.0 drain to source voltage and 20.0 gate to source voltage

Power Rating Per Characteristic:

14.4 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Precious Material And Location:

Terminal surfaces gold

Precious Material:

Gold

Test Data Document:

57057-8880200052 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 ribbon and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0